LOW-VOLTAGE 20-BIT BUS SWITCH WITH PRECHARGED OUTPUTS

IDT74CBTLV16800

FEATURES:

- **5Ω A/B bi-directional switch**
- **Isolation Under Power-Off Conditions**
- **Over-voltage tolerant**
- **Latch-up performance exceeds 100mA**
- **Vcc = 2.3V - 3.6V, normal range**
- **ESD >2000V per MIL-STD-883, Method 3015; >200V using machine model (C = 200pF, R = 0)**
- **Available in SSOP, TSSOP, and TVSOP packages**

APPLICATIONS:

- **3.3V High Speed Bus Switching and Bus Isolation**

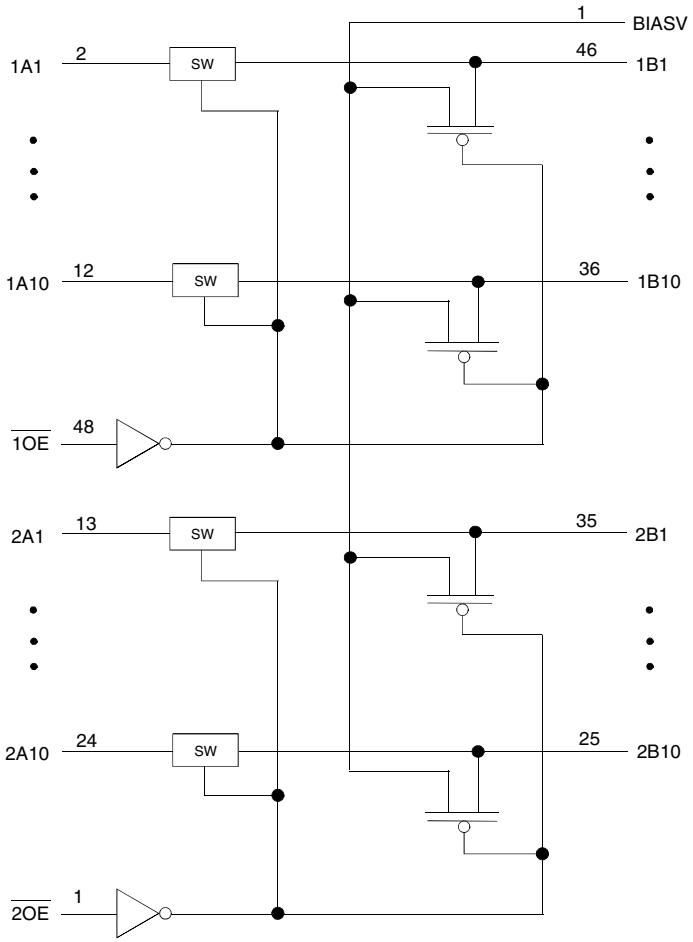
DESCRIPTION:

The CBTLV16800 provides 20-bits of high-speed bus switching with low on-state resistance of the switch allowing connections to be made with minimal propagation delay. The device also precharges the B port to a user-selectable bias voltage (BIASV) to minimize live-insertion noise.

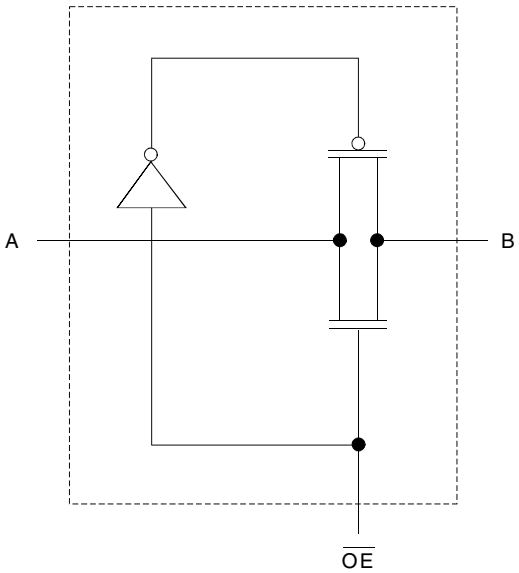
The CBTLV16800 is organized as dual 10-bit bus switches with two different output-enable ($\overline{OE}$) control inputs. When $\overline{OE}$ is low, the corresponding 10-bit bus switch is on and port A is connected to port B. When $\overline{OE}$ is high, the switch is open, and a high impedance state exists between the two ports, and port B is precharged to BIASV through the equivalent of a 10-kΩ resistor.

To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to Vcc through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

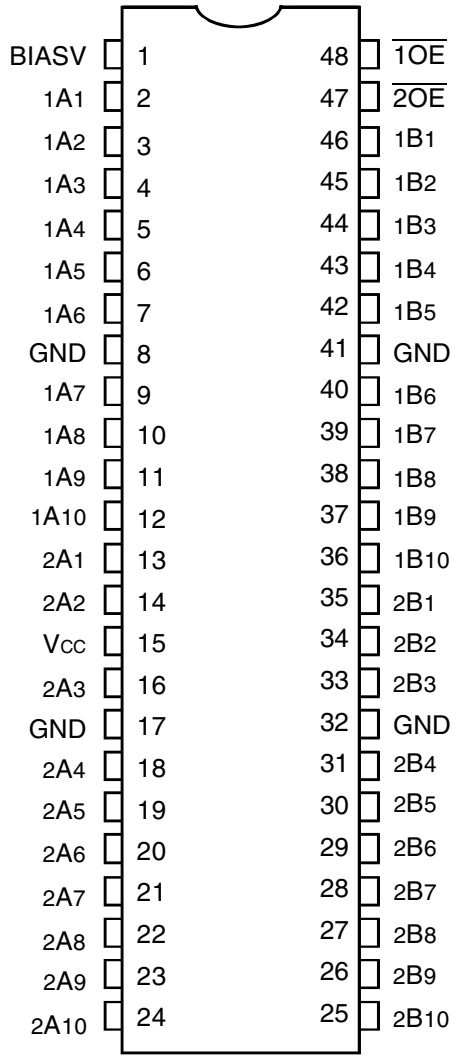
FUNCTIONAL BLOCK DIAGRAM



SIMPLIFIED SCHEMATIC, EACH SWITCH



PIN CONFIGURATION



SSOP/ TSSOP/ TVSOP
TOP VIEW

ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max.	Unit
V_{CC}	Supply Voltage Range	–0.5 to 4.6	V
BIASV	Bias Voltage Range, V_I	–0.5 to 4.6	V
V_I	Input Voltage Range	–0.5 to 4.6	V
	Continuous Channel Current	128	mA
I_{IK}	Input Clamp Current, $V_{I/O} < 0$	–50	mA
T_{STG}	Storage Temperature Range	–65 to +150	°C

NOTE:
1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

FUNCTION TABLE (EACH 10-BIT BUS SWITCH)(1)

Input $\overline{OE}$	Inputs/Outputs
L	A-Port = B-Port
H	A-Port = Z B-Port = BIASV

NOTE:
1. H = HIGH Voltage Level
   L = LOW Voltage Level
   Z = High-Impedance

OPERATING CHARACTERISTICS(1)

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
V_{CC}	Supply Voltage		2.3	3.6	V
BIASV	Bias Voltage		1.3	V_{CC}	V
V_{IH}	High-Level Control Input Voltage	V_{CC} = 2.3V to 2.7V	1.7	—	V
		V_{CC} = 2.7V to 3.6V	2	—	
V_{IL}	Low-Level Control Input Voltage	V_{CC} = 2.3V to 2.7V	—	0.7	V
		V_{CC} = 2.7V to 3.6V	—	0.8	
T_A	Operating Free-Air Temperature		–40	+85	°C

NOTE:
1. All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:
Operating Condition: T_A = –40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
V_{IK}	Control Inputs, Data I/O	V_{CC} = 3V, I_I = –18mA		—	—	–1.2	V
I_I	Control Inputs	V_{CC} = 3.6V, V_I = V_{CC} or GND		—	—	±1	µA
I_{OZ}	Data I/O	V_{CC} = 3.6V, V_O = 0V or 3.6V switch disabled		—	—	5	µA
I_{OFF}	A Port	V_{CC} = 0V, V_I or V_O = 0V or 3.6V		—	—	10	µA
I_O		V_{CC} = 3V, BIASV = 2.4V, V_O = 0, $\overline{OE}$ = V_{CC}		| 0.25 |	—	—	mA
I_{CC}		V_{CC} = 3.6V, I_O = 0, V_I = V_{CC} or GND		—	—	10	µA
ΔI_{CC}[1]	Control Inputs	V_{CC} = 3.6V, one input at 3V, other inputs at V_{CC} or GND		—	—	300	µA
C_I	Control Inputs	V_I = 3V or 0		—	4	—	pF
$C_{IO(OFF)}$		V_O = 3V or 0, switch off, BIASV = open, $\overline{OE}$ = V_{CC}		—	6.5	—	pF
R_{ON}	V_{CC} = 2.3V Typ. at V_{CC} = 2.5V	V_I = 0	I_I = 64mA	—	5	9	Ω
			I_I = 24mA	—	5	9	
		V_I = 1.7V	I_I = 15mA	—	25	35	
	V_{CC} = 3V	V_I = 0	I_I = 64mA	—	5	7	
			I_I = 24mA	—	5	7	
		V_I = 2.4V	I_I = 15mA	—	10	15	

NOTES:

1. The increase in supply current is attributable to each input that is at the specified voltage level rather than V_{CC} or GND.
2. This is measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

SWITCHING CHARACTERISTICS

Symbol	Parameter	V_{CC} = 2.5V ± 0.2V		V_{CC} = 3.3V ± 0.3V		Unit
		Min.	Max.	Min.	Max.	
t_{PD}[1]	Propagation Delay A to B or B to A	—	0.15	—	0.25	ns
t_{PZH}	BIASV = GND $\overline{OE}$ to A or B	2.9	7.7	2.2	5.5	ns
t_{PZL}	BIASV = 3V $\overline{OE}$ to A or B	2.8	6.4	2.1	5.3	ns
t_{PHZ}	BIASV = GND $\overline{OE}$ to A or B	1.4	6.8	2.6	7.6	ns
t_{PLZ}	BIASV = 3V $\overline{OE}$ to A or B	1.3	4.2	1.5	5.1	ns

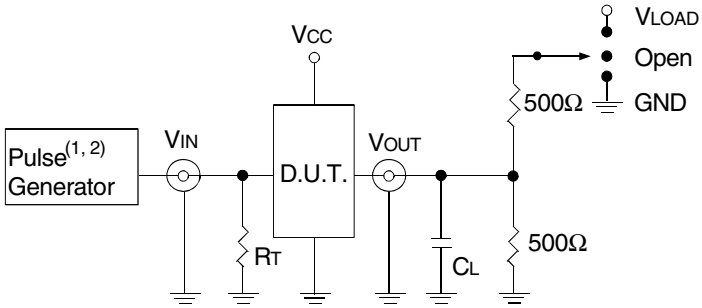
NOTE:

1. The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impededance).

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

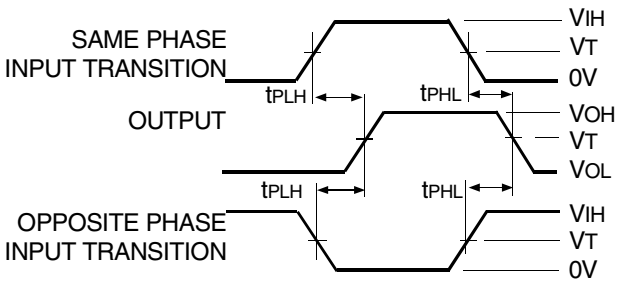
Symbol	$V_{CC}^{(1)}$= 3.3V±0.3V	$V_{CC}^{(2)}$= 2.5V±0.2V	Unit
V_{LOAD}	6	2 x Vcc	V
V_{IH}	3	Vcc	V
V_T	1.5	Vcc / 2	V
V_{LZ}	300	150	mV
V_{HZ}	300	150	mV
C_L	50	30	pF



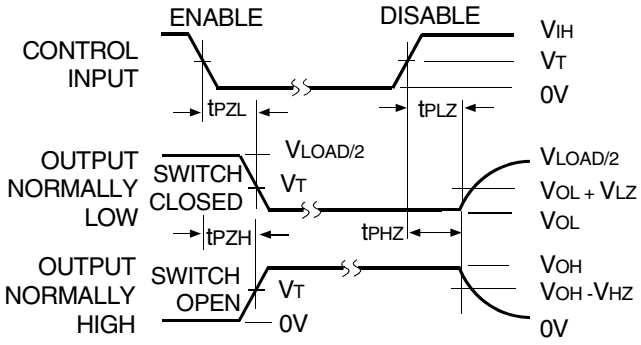
Test Circuits for All Outputs

DEFINITIONS:
C_L = Load capacitance: includes jig and probe capacitance.
R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:
1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2.5ns; t_R ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2ns; t_R ≤ 2ns.



Propagation Delay



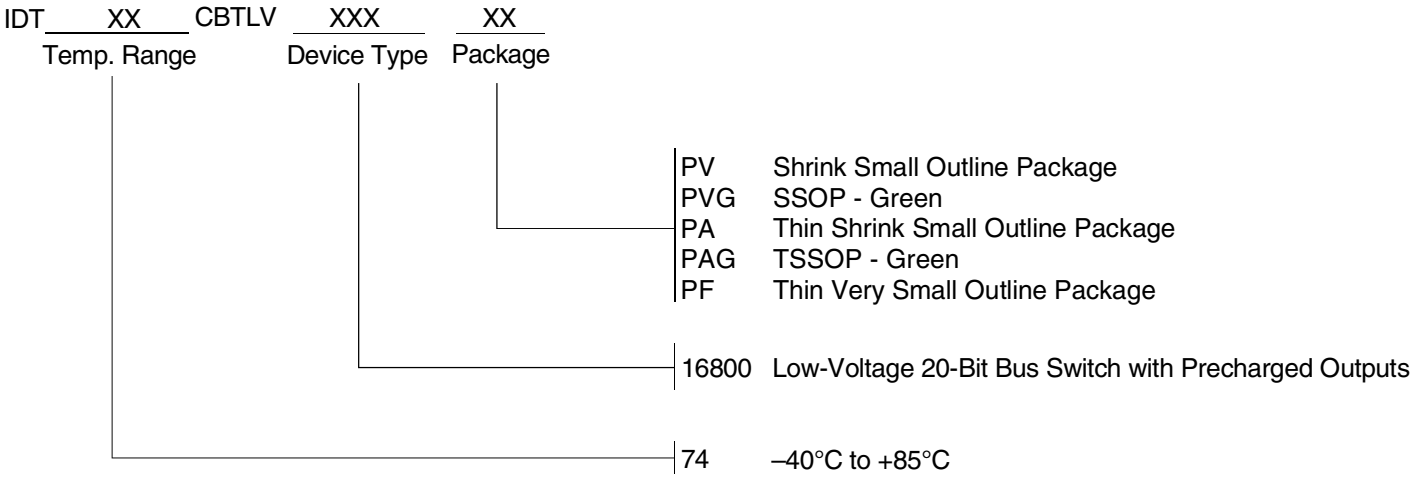
NOTE:
1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

Enable and Disable Times

SWITCH POSITION

Test	Switch
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND
t_{PD}	Open

ORDERING INFORMATION



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